MAR 8 1 2006 forney's Docket No. <u>42P16680</u> Confirmation No.: 9123

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Justin K. Brask, et al.

Application No.: 10/750,061

Filed:

December 30, 2003

For: NONPLANAR TRANSISTOR WITH

METAL GATE ELECTRODES

Examiner: Lindsay Jr., Walter

Lee

Art Unit: 2812

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Enclosed is a copy of Information Disclosure Citation Form PTO-1449 or PTO/SB/08 together with copies of the documents cited on that form, except for copies not required to be submitted (e.g., copies of U.S. patents and U.S. published patent applications). It is respectfully requested that the cited documents be considered and that the enclosed copy of Information Disclosure Citation Form PTO-1449 or PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

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Dianne Neathery

(Typed or printed name of person mailing correspondence)

(Signature of person mailing correspondence)

Appl. No.: 10/750,061 Filing Date: December 30, 2003 - 1/2 -

LJV/cak (10/27/04) Atty. Docket: 42P16680 Pursuant to 37 C.F.R. § 1.97, the submission of this Information

Disclosure Statement is not to be construed as a representation that a search

has been made and is not to be construed as an admission that the information

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Pursuant to 37 C.F.R. § 1.97, this Information Disclosure Statement is being submitted under one of the following (as indicated by an "X" to the left of the appropriate paragraph):

	37 C.F.R. §1.97(b).
X	37 C.F.R. §1.97(c). If so, then enclosed with this Information Disclosure Statement is one of the following:
X	_ A statement pursuant to 37 C.F.R. §1.97(e) or
	A check for \$180.00 for the fee under 37 C.F.R. § 1.17(p).
	37 C.F.R. §1.97(d). If so, then enclosed with this Information Disclosure Statement are the following:
	(1) A statement pursuant to 37 C.F.R. §1.97(e); and

(2) A check for \$180.00 for the fee under 37 C.F.R. §1.17(p) for submission of the Information Disclosure Statement.

If there are any additional charges, please charge Deposit Account No. 02-2666.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Dated: March 29, 2006

Michael A. Bernadicou

Reg. No. 35,934

12400 Wilshire Blvd. Seventh Floor Los Angeles, CA 90025 (408) 720-8300

Appl. No.: 10/750,061

Filing Date: December 30, 2003

- 2/2 -

LJV/cak (10/27/04) Atty. Docket: 42P16680 Attorney's Docket No. 42P16680

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Lindsay Jr., Walter Lee

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Examiner:

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STATEMENT UNDER 37 C.F.R. §1.97(e)

Sir:

I hereby certify (as indicated by an "X" to the left of the appropriate

paragraph):

That each item of information contained in the accompanying Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Information Disclosure Statement.

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(Date of Deposit)

Dianne Neathery

(Typed or printed name of person mailing correspondence)

we Neather 3/29/6 (Signature of person mailing correspondence)

Application No.: 10/750,061 - 1/2 -

Docket No.: 42P16680

That no item of information contained in the accompanying Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned attorney after making reasonable inquiry, no item of information contained in the Information Disclosure Statement was known to any individual designated in §1.56(c) more than three months prior to the filing the Information Disclosure Statement.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Dated: March 29, 2006

Michael A. Bernadicou

Reg. No. 35,934

12400 Wilshire Blvd. Seventh Floor Los Angeles, CA 90025 (408) 720-8300

Application No.: 10/750,061 - 2/2 - Docket No.: 42P16680

Substitute for Form 1449/PTO					Complete if Known		
DEINFORMATION DISCLOSURE				Application Number	10/750,061		
OF ETHEORMATION DISCLOSURE					Filing Date	December 30, 2003	
/	/ STATEMENT BY APPLICANT					Justin K. Brask, et al.	
STATEMENT BY APPLICANT (use as many sheets as necessary)					First Named Inventor: Art Unit	2812	
					Examiner Name	Lindsay Jr., Walter Lee	
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Sheet IR	DEMAN 1	 	of	3	Attorney Docket No.:	42P16680	
			U.S. PATE	NT DOCUMENT	rs		
Examiner Initials*	Cite No.		Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
•		Numb	er-Kind Code ² (If known)			l ignios i ppos.	
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Substitute for Form 1449/PTO	Complete if Known		
INFORMATION DISCL	OSURE	Application Number	10/750,061
	Filing Date	December 30, 2003	
OIP E STATEMENT BY APP	First Named Inventor:	Justin K. Brask, et al.	
(use as many sheets as necess	sary)	Art Unit	2812
MAR 8 1 2006	Examiner Name	Lindsay Jr., Walter Lee	
Sheet 2 of	3	Attorney Docket No.:	42P16680

Examiner Cite	Cite	Foreign Patent Document	Publication	Name of Patentee or	Pages, Columns,	Т
·Initials*	No. ¹	Country Code ³ Number ⁴ Kind Code ⁵ (if known)	Date MM-DD-YYYY	Applicant of Cited Document	Lines, Where Relevant Passages or Relevant Figures Appear	•
		WO 2004/059726 A1	07-15-2004	IBM Corporation		
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		NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T			
		International Search Report PCT/US2005/033439, mailed 1/31/2006 (7 pgs.)				
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		SUNG MIN KIM, et al., "A Novel Multi-channel Field Effect Transistr (McFET) on Bulk Si for High Performance Sub-80nm Application, IEDM 04-639, 2004 IEEE, pgs. 27.4.1-27.4.4				
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aminer gnature		Date Considered				

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Substitute for Form 1449/PTO		Complete if Known		
OLPEINFORMATIO	N DISCLOSU	RF	Application Number	10/750,061
			Filing Date	December 30, 2003
S TATEMENT	BY APPLICA	First Named Inventor:	Justin K. Brask, et al.	
MAR 3 1 2006 (use as many s	heets as necessary)		Art Unit	2812
Sheet 3		Examiner Name	Lindsay Jr., Walter Lee	
Sheet 3	of	3	Attorney Docket No.:	42P16680

NON PATENT LITERATURE DOCUMENTS					
Examiner • Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²		
		WEIZE XIONG, et al., "Improvement of FinFET Electrical Characteristics by Hydrogen Annealing" IEEE Electron Device Letters, Vol. 25, No. 8, August 2004, XP-001198998, pgs. 541-543			
		FU-LIANG YANG, et al., "5nm-Gate Nanowire FinFET" 2004 Symposium on VLSI Technology Digest of Technical Papers, 2004 IEEE, pgs. 196-197			
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